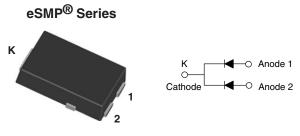
### Vishay Semiconductors

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# Hyperfast Rectifier, 2 x 3 A FRED Pt<sup>®</sup>



SMPC (TO-277A)

### LINKS TO ADDITIONAL RESOURCES



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PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	2 x 3 A						
V <sub>R</sub>	100 V						
V <sub>F</sub> at I <sub>F</sub>	0.75 V						
t <sub>rr (typ.)</sub>	27 ns						
T <sub>J</sub> max.	175 °C						
Package	SMPC (TO-277A)						
Circuit configuration	Common cathode						

#### FEATURES

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260  $^{\circ}\mathrm{C}$
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

#### **MECHANICAL DATA**

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM R	ATINGS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V <sub>RRM</sub>		100	V
Average rectified forward current	per device	I	T 165 °C	6	
Average rectilied forward current	per diode	IF(AV)	T <sub>Sp</sub> = 165 °C	3	^
Non-repetitive peak surge current	per device	l		150	A
Non-repetitive peak surge current	per diode	IFSM	$T_J = 25 \ ^{\circ}C$ , 6 ms square pulse	80	
Operating junction and storage ten	nperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J$ = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	100	-	-	
Forward voltage, per diode	VF	I <sub>F</sub> = 3 A	-	0.87	0.94	V
r orward voltage, per diode	۷F	I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C	-	0.75	0.79	
Reverse leakage current, per diode	1	$V_{R} = V_{R}$ rated	-	-	2	
neverse leakage current, per diode	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	0.7	10	μA
Junction capacitance	CT	V <sub>R</sub> = 100 V	-	13	-	pF

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RoHS

COMPLIANT

HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t =$	= 50 A/µs, V <sub>R</sub> = 30 V	-	27	-	
Poverse recovery time	+	$I_{\rm F} = 0.5 \text{ A}, I_{\rm R} = 1000$	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		-	25	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	20	-	A nC
		T <sub>J</sub> = 125 °C		-	26	-	
Deels receiver a surrent		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 3 A dI <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 160 V	-	2.4	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	3.8	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	23	-	
		T <sub>J</sub> = 125 °C		-	50	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C	
Thermal resistance, junction to mount, per diode	R <sub>thJM</sub>		-	2.8	4	°C/W	
Approximate weight				0.1		g	
Approximate weight				0.0035		oz.	
Marking device		Case style SMPC (TO-277A)	NCH1				

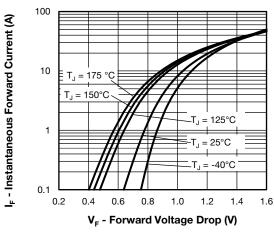


Fig. 1 - Typical Forward Voltage Drop Characteristics

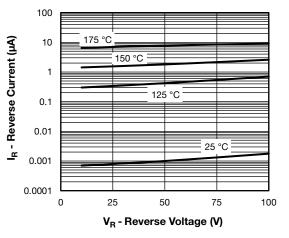
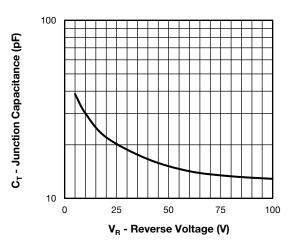


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

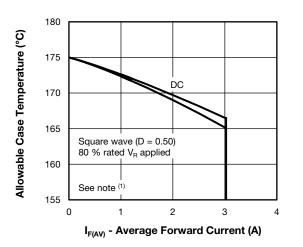


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

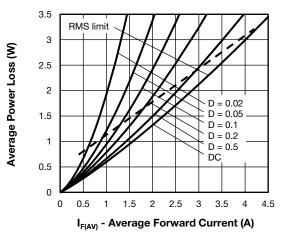


Fig. 5 - Forward Power Loss Characteristics

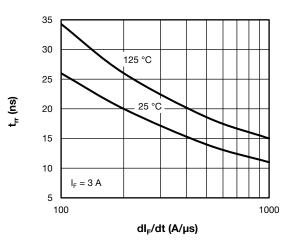


Fig. 6 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

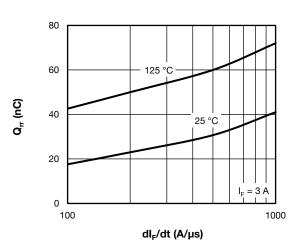


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

(1)

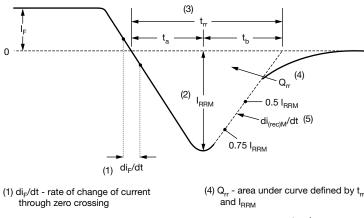
 $Formula used: T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = forward power loss = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 5);$  $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$ 

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3

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 $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$ 

(3) t<sub>rr</sub> - reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.

(2)  ${\rm I}_{\rm RRM}$  - peak reverse recovery current

(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 8 - Reverse Recovery Waveform and Definitions

#### **ORDERING INFORMATION TABLE**

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1 2 3 4 5 6 7 1 - Vishay Semiconductors product 2 - Current rating (6 = 6 A) 3 - Circuit configuration: C = common cathode 4 - S = SMPC package 5 - Process type, H = hyper fast recovery 6 - Voltage code (01 = 100 V)	Device code	′S-	6	с	S	Н	01	-M3
<ul> <li>2 - Current rating (6 = 6 A)</li> <li>3 - Circuit configuration: C = common cathode</li> <li>4 - S = SMPC package</li> <li>5 - Process type, H = hyper fast recovery</li> </ul>	(	1	2	3	4	5	6	7
<ul> <li>3 - Circuit configuration: C = common cathode</li> <li>4 - S = SMPC package</li> <li>5 - Process type, H = hyper fast recovery</li> </ul>	1			•		•	oduct	
<ul> <li>4 - S = SMPC package</li> <li>5 - Process type, H = hyper fast recovery</li> </ul>					•			
H = hyper fast recovery	4	-						
<b>6</b> - Voltage code $(01 = 100 \text{ V})$	5	-			-	very		
7M3 = halogen-free, RoHS-compliant, and to	6			-			compli	ant and

ORDERING INFORMATI	ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-6CSH01-M3/86A	1500	1500	7" diameter plastic tape and reel				
VS-6CSH01-M3/87A	6500	6500	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95570				
Part marking information	www.vishay.com/doc?95565				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96378				

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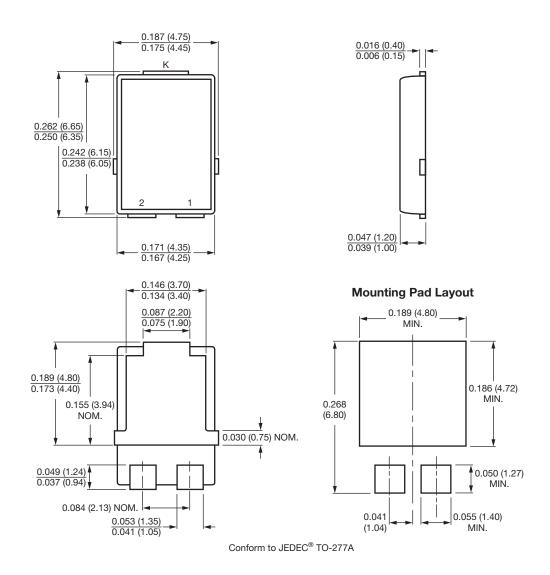
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# TO-277A (SMPC)

### **DIMENSIONS** in inches (millimeters)





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